

Power Matters.™

[Home](#) ▶ [2N6061 \(#23886\)](#)

Products

- ▶ [Product Directory](#)
- ▶ [Applications](#)
- ▶ [Parametric Search](#)

2N6061 (#23886)

Product Status

■ In Production

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Overview

Diagrams

Electrical Rating	Symbol	Min	Typ	Max	Unit
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$			1.80	V
DC Current Gain	HFE	20.00		120.00	

Maximum Electrical Rating	Symbol	Min	Typ	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	$V_{BR(CBO)}$			100.00	V
Collector Current (dc)	I_C			50.00	A
Collector-Emitter Voltage (Base Open)	V_{CEO}			100.00	V
Emitter-Base Voltage (Collector Open)	V_{EBO}			8.00	V
Power Dissipation, Total	P_T			262.00	W

This part can be found in the following product categories:

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